

具有 ±15kV ESD 保护功能的 3V 至 5.5V 多通道 RS-232 线路驱动器和接收器

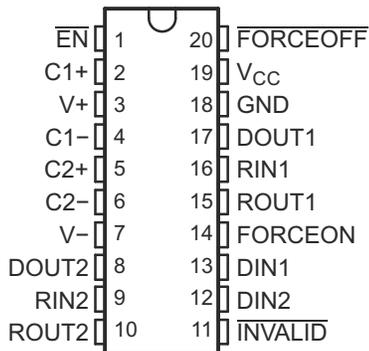
1 特性

- 为 RS-232 总线引脚提供 ESD 保护
 - ±15kV 人体放电模型 (HBM)
 - ±8kV IEC61000-4-2 接触放电
 - ±15kV IEC61000-4-2 气隙放电
- 符合或超出 TIA/EIA-232-F 和 ITU v.28 标准的要求
- 由 3V 至 5.5V V_{CC} 电源供电
- 速率高达 500kbit/s
- 两个驱动器和两个接收器
- 低待机电流: 1 μ A (典型值)
- 外部电容器: 4 \times 0.1 μ F
- 支持 5V 逻辑输入及 3.3V 电源
- 适合 SNx5C3223E 的备选高速引脚兼容器件 (1Mbit/s)

2 应用

- 电池供电型系统
- PDA
- 笔记本电脑
- 便携式计算机
- 掌上电脑
- 手持设备

DB, DW, OR PW PACKAGE
(TOP VIEW)



3 说明

MAX3223E 由两个线路驱动器、两个线路接收器和一个双电荷泵电路组成, 具有引脚对引脚 (串行端口连接引脚, 包括 GND) ±15kV ESD 保护。该器件符合 TIA/EIA-232-F 的要求并在异步通信控制器与串行端口连接器之间提供电气接口。电荷泵和四个小型外部电容器支持由 3V 至 5.5V 单电源供电。该器件以高达 500kbit/s 的典型数据信号传输速率运行, 驱动器输出电压摆率最大为 30V/ μ s。

串行端口处于非活动状态时, 可提供灵活的电源管理控制选项。当 FORCEON 为低电平且 FORCEOFF 为高电平时, 自动断电功能启用。在这种运行模式下, 如果器件未检测到有效的 RS-232 信号, 则禁用驱动器输出。如果 FORCEOFF 设定为低电平且 EN 为高电平, 则驱动器和接收器均关闭, 且电源电流降低至 1mA。断开串行端口的连接或关闭外围驱动器会导致发生自动断电情况。当 FORCEON 和 FORCEOFF 均为高电平时可禁用自动断电。启用自动断电的情况下, 向任何接收器输入施加有效信号时, 器件会自动激活。INVALID 输出用于通知用户任何接收器输入端是否存在 RS-232 信号。如果任何接收器输入电压大于 2.7V 或小于 -2.7V, 或者介于 -0.3V 至 0.3V 之间的时间少于 30 μ s, 则 INVALID 为高电平 (有效数据)。如果接收器输入电压在 -0.3V 至 0.3V 之间的时间超过 30 μ s, 则 INVALID 为低电平 (无效数据)。有关接收器输入电平的信息, 请参阅图 5-4。

封装信息

| 器件型号 | 封装 ⁽¹⁾ | 封装尺寸 ⁽²⁾ |
|----------|-------------------|------------------------|
| MAX3223E | SOIC (DW, 20) | 12.8mm \times 10.3mm |
| | SSOP (DB, 20) | 7.2mm \times 7.8mm |
| | TSSOP (PW, 20) | 6.5mm \times 6.4mm |

(1) 有关详细信息, 请参阅节 10。

(2) 封装尺寸 (长 \times 宽) 为标称值, 并包括引脚 (如适用)。



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4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

| | | MIN | MAX | UNIT | |
|------------------|-----------------------------------------------------|---------------------------------|--------|-----------------------|---|
| V _{CC} | Supply voltage range | - 0.3 | 6 | V | |
| V+ | Positive-output supply voltage range ⁽²⁾ | - 0.3 | 7 | V | |
| V- | Negative-output supply voltage range ⁽²⁾ | 0.3 | - 7 | V | |
| V+ - V- | Supply voltage difference ⁽²⁾ | | 13 | V | |
| V _I | Input voltage range | Driver (FORCEOFF, FORCEON, EN) | - 0.3 | 6 | V |
| | | Receiver | - 25 | 25 | |
| V _O | Output voltage range | Driver | - 13.2 | 13.2 | V |
| | | Receiver (INVALID) | - 0.3 | V _{CC} + 0.3 | |
| T _J | Operating virtual junction temperature | | 150 | °C | |
| T _{stg} | Storage temperature range | - 65 | 150 | °C | |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to network GND.

4.2 Recommended Operating Conditions

See 图 7-1, and ⁽¹⁾

| | | MIN | NOM | MAX | UNIT | |
|-----------------|---------------------------------------------|----------------------------|-------------------------|------|------|---|
| Supply voltage | | V _{CC} = 3.3 V | 3 | 3.3 | 3.6 | V |
| | | V _{CC} = 5 V | 4.5 | 5 | 5.5 | |
| V _{IH} | Driver and control high-level input voltage | DIN, EN, FORCEOFF, FORCEON | V _{CC} = 3.3 V | 2 | | V |
| | | | V _{CC} = 5 V | 2.4 | | |
| V _{IL} | Driver and control low-level input voltage | DIN, EN, FORCEOFF, FORCEON | | 0.8 | V | |
| V _I | Driver and control input voltage | DIN, EN, FORCEOFF, FORCEON | | 0 | 5.5 | V |
| | Receiver input voltage | | | - 25 | 25 | V |
| T _A | Operating free-air temperature | MAX3223EC | 0 | 70 | °C | |
| | | MAX3223EI | - 40 | 85 | | |

- (1) Test conditions are C1 - C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2 - C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

4.3 ESD Ratings

| | | VALUE | UNIT | | |
|--------------------|-------------------------|-----------------------------------------------------------------------|--------------------------------------------------|--------|---|
| V _(ESD) | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | All pins except RIN1, RIN2, DOUT1 and DOUT2 pins | ±3000 | V |
| | | Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾ | RIN1, RIN2, DOUT1 and DOUT2 pins to GND | ±15000 | |
| | | | All pins | ±1500 | |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

4.4 ESD Ratings - IEC Specifications

| | | VALUE | UNIT |
|--------------------|-------------------------|------------------------------------------------|---------|
| V _(ESD) | Electrostatic discharge | IEC 61000-4-2 Contact Discharge ⁽¹⁾ | ±8000 |
| | | IEC 61000-4-2 Air-gap Discharge ⁽¹⁾ | ±15,000 |

(1) A minimum of 1-μF capacitor between V_{CC} and GND is required to meet the specified IEC 61000-4-2 rating.

4.5 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | DB (SOIC) | DW (SOIC) | PW (TSSOP) | UNIT |
|-------------------------------|----------------------------------------------|-----------|-----------|------------|------|
| | | 20 PINS | 20 PINS | 20 PINS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 87.2 | 76.8 | 89.7 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 41.1 | 39.6 | 29.0 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 43.3 | 41.5 | 41.9 | °C/W |
| ψ _{JT} | Junction-to-top characterization parameter | 9.2 | 12.6 | 1.9 | °C/W |
| ψ _{JB} | Junction-to-board characterization parameter | 42.7 | 40.9 | 41.3 | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

4.6 Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 5-5](#)) and ⁽¹⁾

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽²⁾ | MAX | UNIT |
|-----------------|-----------------------|-------------------------|---------------------------------------------------------------------------------------------------------|--------------------|-----|------|
| I _I | Input leakage current | EN, FORCEOFF, FORCEON | | ±0.01 | ±1 | μA |
| I _{CC} | Supply current | Auto-powerdown disabled | V _{CC} = 3.3 V or 5 V, T _A = 25°C, No load, FORCEOFF and FORCEON at V _{CC} | 0.3 | 1.3 | mA |
| | | Powered off | No load, FORCEOFF at GND | 1 | 10 | μA |
| | | Auto-powerdown enabled | No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded | 1 | 10 | |

(1) Test conditions are C1 – C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2 – C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

4.7 Driver Section

4.7.1 Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 5-5](#)) and ⁽¹⁾

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽²⁾ | MAX | UNIT |
|-----------------|---------------------------------------------|------------------------------------------------------------------------------------|-----|--------------------|-----|------|
| V _{OH} | High-level output voltage | DOOUT at R _L = 3 kΩ to GND | 5 | 5.4 | | V |
| V _{OL} | Low-level output voltage | DOOUT at R _L = 3 kΩ to GND | -5 | -5.4 | | V |
| I _{IH} | High-level input current | V _I = V _{CC} | | ±0.01 | ±1 | μA |
| I _{IL} | Low-level input current | V _I at GND | | ±0.01 | ±1 | μA |
| I _{OS} | Short-circuit output current ⁽³⁾ | V _{CC} = 3.6 V, V _O = 0 V | | ±35 | ±60 | mA |
| | | V _{CC} = 5.5 V, V _O = 0 V | | | | |
| r _o | Output resistance | V _{CC} , V ₊ , and V ₋ = 0 V, V _O = ±2 V | 300 | 10M | | Ω |
| I _{OZ} | Output leakage current | FORCEOFF = GND, V _{CC} = 3 V to 3.6 V, V _O = ±12 V | | | ±25 | μA |
| | | FORCEOFF = GND, V _{CC} = 4.5 V to 5.5 V, V _O = ±12 V | | | ±25 | |

(1) Test conditions are C1 – C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2 – C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

- (3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

4.7.2 Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see 图 5-5) and ⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | MIN | TYP ⁽²⁾ | MAX | UNIT |
|-------------|---------------------------------------------|--------------------------------------------------------------------------------|----------------------------------------------------|-----|--------------------|-----|------------------|
| | Maximum data rate | $C_L = 1000 \text{ pF}$, One DOUT switching, | $R_L = 3 \text{ k}\Omega$, See 图 5-1 | 250 | 500 | | kbit/s |
| $t_{sk(p)}$ | Pulse skew ⁽³⁾ | $C_L = 150 \text{ pF}$ to 2500 pF , See 图 5-2 | $R_L = 3 \text{ k}\Omega$ to $7 \text{ k}\Omega$, | | 100 | | ns |
| SR(tr) | Slew rate, transition region (See 图 5-1) | $R_L = 3 \text{ k}\Omega$ to $7 \text{ k}\Omega$, $V_{CC} = 3.3 \text{ V}$ | $C_L = 150 \text{ pF}$ to 1000 pF | 6 | | 30 | V/ μs |
| | | | $C_L = 150 \text{ pF}$ to 2500 pF | 4 | | 30 | |

- (1) Test conditions are $C_1 - C_4 = 0.1 \text{ }\mu\text{F}$ at $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $C_1 = 0.047 \text{ }\mu\text{F}$, $C_2 - C_4 = 0.33 \text{ }\mu\text{F}$ at $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$.
(2) All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25^\circ\text{C}$.
(3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

4.7.3 ESD Protection

| | | TYP | UNIT |
|------------------------|---------------------------------|----------|------|
| Driver outputs (DOUTx) | Human-Body Model (HBM) | ± 15 | kV |
| | IEC61000-4-2, Air-Gap Discharge | ± 15 | |
| | IEC61000-4-2, Contact Discharge | ± 8 | |

4.8 Receiver Section

4.8.1 Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see 图 7-1) and ⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | MIN | TYP ⁽²⁾ | MAX | UNIT |
|-----------|------------------------------------------|-----------------------------------------------|--|----------------|--------------------|-----|------------------|
| V_{OH} | High-level output voltage | $I_{OH} = -1 \text{ mA}$ | | $V_{CC} - 0.6$ | $V_{CC} - 0.1$ | | V |
| V_{OL} | Low-level output voltage | $I_{OL} = 1.6 \text{ mA}$ | | | | 0.4 | V |
| V_{IT+} | Positive-going input threshold voltage | $V_{CC} = 3.3 \text{ V}$ | | | 1.6 | 2.4 | V |
| | | $V_{CC} = 5 \text{ V}$ | | | 1.9 | 2.4 | |
| V_{IT-} | Negative-going input threshold voltage | $V_{CC} = 3.3 \text{ V}$ | | 0.6 | 1.1 | | V |
| | | $V_{CC} = 5 \text{ V}$ | | 0.6 | 1.4 | | |
| V_{hys} | Input hysteresis ($V_{IT+} - V_{IT-}$) | | | | 0.5 | | V |
| I_{OZ} | Output leakage current | $EN = V_{CC}$ | | | ± 0.05 | | μA |
| r_i | Input resistance | $V_i = \pm 3 \text{ V}$ to $\pm 25 \text{ V}$ | | 3 | 5 | | $\text{k}\Omega$ |

- (1) Test conditions are $C_1 - C_4 = 0.1 \text{ }\mu\text{F}$ at $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $C_1 = 0.047 \text{ }\mu\text{F}$, $C_2 - C_4 = 0.33 \text{ }\mu\text{F}$ at $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$.
(2) All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25^\circ\text{C}$.

4.8.2 Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) ⁽¹⁾

| PARAMETER | | TEST CONDITIONS | | TYP ⁽²⁾ | UNIT |
|-------------|---------------------------------------------------|----------------------------------------------------------------|--|--------------------|------|
| t_{PLH} | Propagation delay time, low- to high-level output | $C_L = 150 \text{ pF}$, See 图 5-3 | | 150 | ns |
| t_{PHL} | Propagation delay time, high- to low-level output | $C_L = 150 \text{ pF}$, See 图 5-3 | | 150 | ns |
| t_{en} | Output enable time | $C_L = 150 \text{ pF}$, $R_L = 3 \text{ k}\Omega$, See 图 5-4 | | 200 | ns |
| t_{dis} | Output disable time | $C_L = 150 \text{ pF}$, $R_L = 3 \text{ k}\Omega$, See 图 5-4 | | 200 | ns |
| $t_{sk(p)}$ | Pulse skew ⁽³⁾ | See 图 5-3 | | 50 | ns |

- (1) Test conditions are $C_1 - C_4 = 0.1 \text{ }\mu\text{F}$ at $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $C_1 = 0.047 \text{ }\mu\text{F}$, $C_2 - C_4 = 0.33 \text{ }\mu\text{F}$ at $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$.

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- (2) All typical values are at $V_{CC} = 3.3\text{ V}$ or $V_{CC} = 5\text{ V}$, and $T_A = 25^\circ\text{C}$.
- (3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

4.8.3 ESD Protection

| | | TYP | UNIT |
|------------------------|---------------------------------|-----|------|
| Receiver inputs (RINx) | Human-Body Model (HBM) | ±15 | kV |
| | IEC61000-4-2, Air-Gap Discharge | ±15 | |
| | IEC61000-4-2, Contact Discharge | ±8 | |

4.9 Auto-Powerdown Section

4.9.1 Electrical Characteristics

 over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [图 5-5](#))

| PARAMETER | | TEST CONDITIONS | | MIN | MAX | UNIT |
|-------------------------|------------------------------------------------------------------------------------|---------------------------------------------------|---------------------|----------------|-----|------|
| $V_{T+}(\text{valid})$ | Receiver input threshold for $\overline{\text{INVALID}}$ high-level output voltage | FORCEON = GND, | FORCEOFF = V_{CC} | | 2.7 | V |
| $V_{T}(\text{valid})$ | Receiver input threshold for $\overline{\text{INVALID}}$ high-level output voltage | FORCEON = GND, | FORCEOFF = V_{CC} | - 2.7 | | V |
| $V_{T}(\text{invalid})$ | Receiver input threshold for $\overline{\text{INVALID}}$ low-level output voltage | FORCEON = GND, | FORCEOFF = V_{CC} | - 0.3 | 0.3 | V |
| V_{OH} | $\overline{\text{INVALID}}$ high-level output voltage | $I_{OH} = 1\text{ mA}$, FORCEOFF = V_{CC} | FORCEON = GND, | $V_{CC} - 0.6$ | | V |
| V_{OL} | $\overline{\text{INVALID}}$ low-level output voltage | $I_{OL} = 1.6\text{ mA}$, FORCEOFF = V_{CC} | FORCEON = GND, | | 0.4 | V |

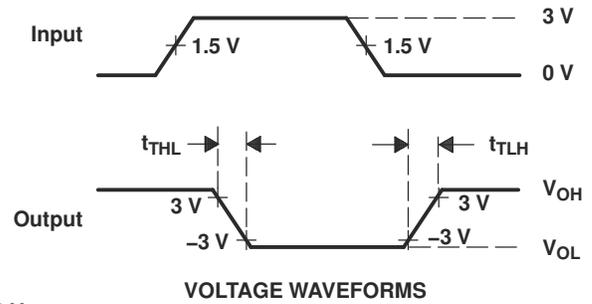
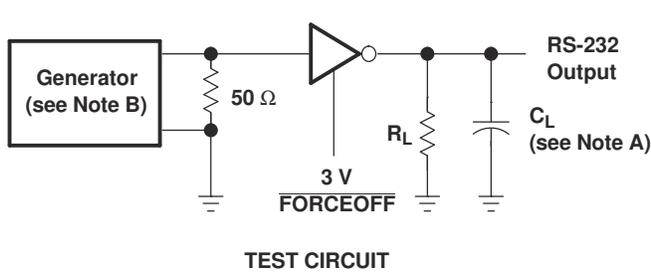
4.9.2 Switching Characteristics

 over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [图 5-5](#))

| PARAMETER | | TYP ⁽¹⁾ | UNIT |
|----------------------|---------------------------------------------------|--------------------|------|
| t_{valid} | Propagation delay time, low- to high-level output | 1 | μs |
| t_{invalid} | Propagation delay time, high- to low-level output | 30 | μs |
| t_{en} | Supply enable time | 100 | μs |

- (1) All typical values are at $V_{CC} = 3.3\text{ V}$ or $V_{CC} = 5\text{ V}$, and $T_A = 25^\circ\text{C}$.

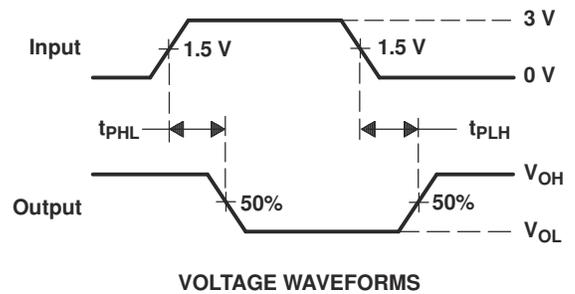
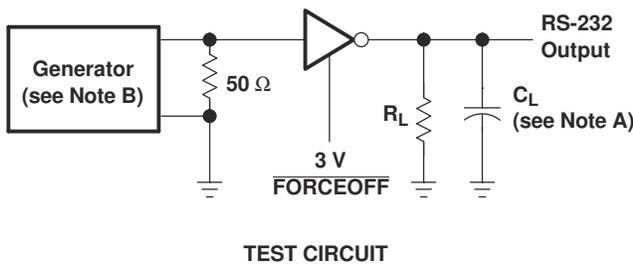
5 Parameter Measurement Information



$$SR(tr) = \frac{6V}{t_{THL} \text{ or } t_{TLH}}$$

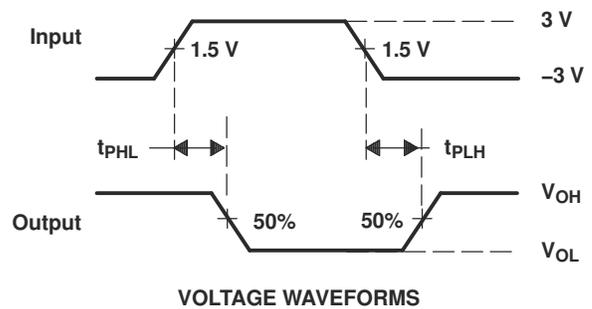
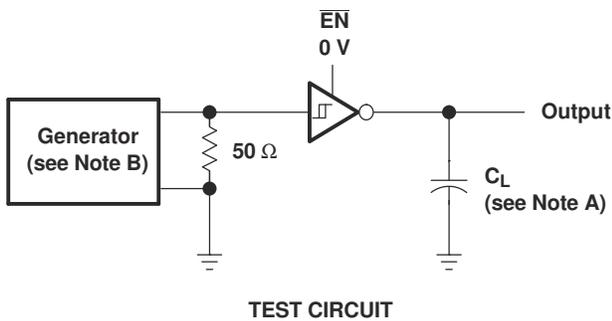
- A. C_L includes probe and jig capacitance.
 B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \leq 10 \text{ ns}$, $t_f \leq 10 \text{ ns}$.

图 5-1. Driver Slew Rate



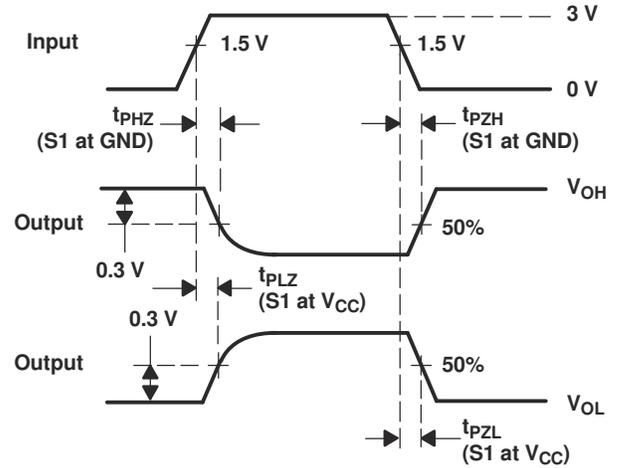
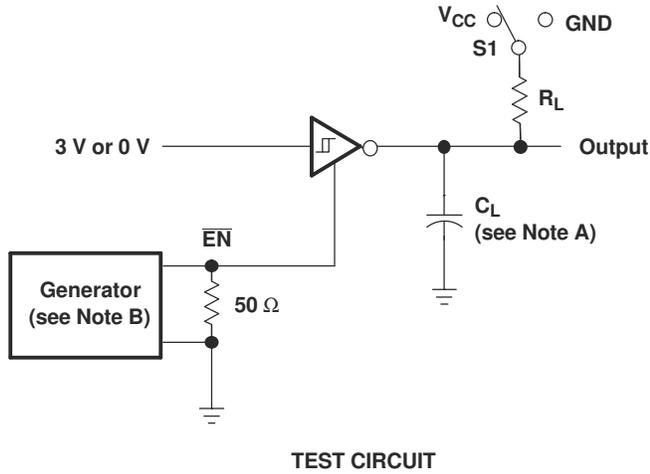
- A. C_L includes probe and jig capacitance.
 B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \leq 10 \text{ ns}$, $t_f \leq 10 \text{ ns}$.

图 5-2. Driver Pulse Skew



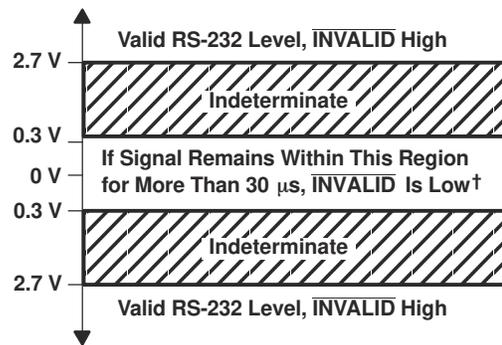
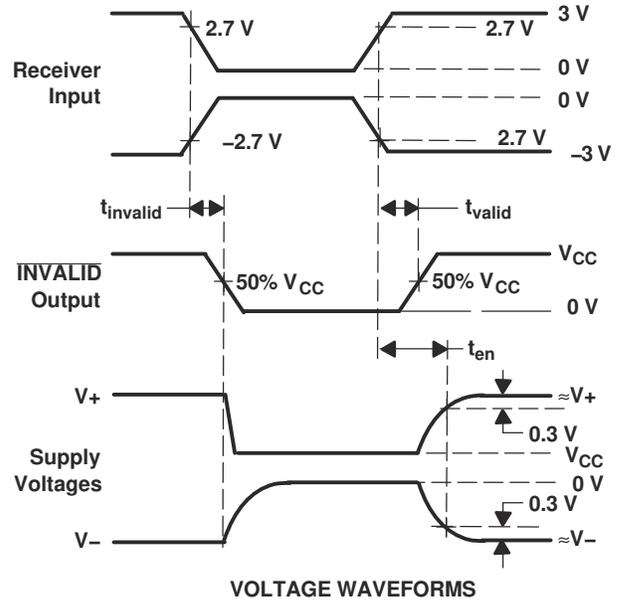
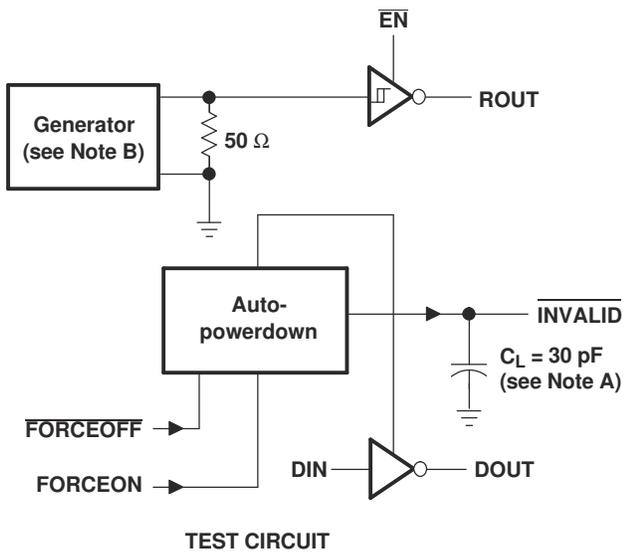
- A. C_L includes probe and jig capacitance.
 B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \leq 10 \text{ ns}$, $t_f \leq 10 \text{ ns}$.

图 5-3. Receiver Propagation Delay Times



- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: $Z_O = 50\ \Omega$, 50% duty cycle, $t_r \leq 10\ \text{ns}$, $t_f \leq 10\ \text{ns}$.

图 5-4. Receiver Enable and Disable Times



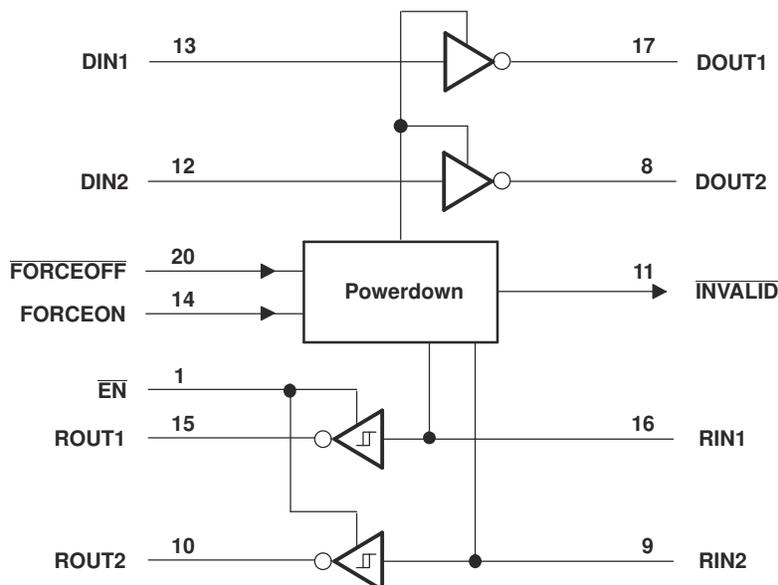
† Auto-powerdown disables drivers and reduces supply current to 1 μ A

- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

图 5-5. INVALID Propagation Delay Times and Supply Enabling Time

6 Detailed Description

6.1 Functional Block Diagram



Pin numbers are for the DB, DW, and PW packages.

图 6-1. Logic diagram (positive logic)

6.2 Device Functional Modes

Function Table (Each Driver)

| INPUTS ⁽¹⁾ | | | | OUTPUT DOUT | DRIVER STATUS |
|-----------------------|---------|----------|------------------------|-------------|-----------------------------------------------|
| DIN | FORCEON | FORCEOFF | VALID RIN RS-232 LEVEL | | |
| X | X | L | X | Z | Powered off |
| L | H | H | X | H | Normal operation with auto-powerdown disabled |
| H | H | H | X | L | |
| L | L | H | Yes | H | Normal operation with auto-powerdown enabled |
| H | L | H | Yes | L | |
| L | L | H | No | Z | Powered off by auto-powerdown feature |
| H | L | H | No | Z | |

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Function Table (Each Receiver)

| INPUTS ⁽¹⁾ | | | OUTPUT DOUT |
|-----------------------|----|------------------------|-------------|
| RIN | EN | VALID RIN RS-232 LEVEL | |
| L | L | X | H |
| H | L | X | L |
| X | H | X | Z |
| Open | L | No | H |

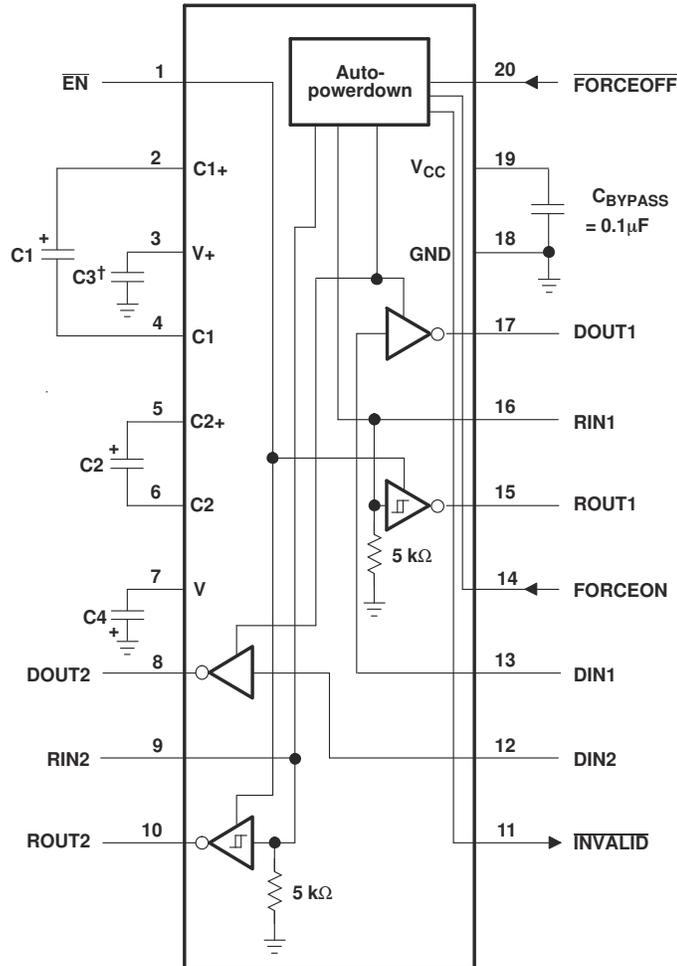
(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

7 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

7.1 Typical Application



† C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

| V _{CC} | C1 | C2, C3, and C4 |
|-----------------|----------|----------------|
| 3.3 V ± 0.3 V | 0.1 μF | 0.1 μF |
| 5 V ± 0.5 V | 0.047 μF | 0.33 μF |
| 3 V to 5.5 V | 0.1 μF | 0.47 μF |

图 7-1. Typical Operating Circuit and Capacitor Values

7.1.1 Detailed Design Procedure

MAX3223E has integrated charge-pump that generates positive and negative rails needed for RS-232 signal levels. Main design requirement is that charge-pump capacitor terminals must be connected with recommended capacitor values. Charge-pump rail voltages and device supply pin must be properly bypassed with ceramic capacitors

(1)

8 Device and Documentation Support

8.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

8.2 支持资源

TI E2E™ 支持论坛 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《[使用条款](#)》。

8.3 Trademarks

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8.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.5 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

9 Revision History

注：以前版本的页码可能与当前版本的页码不同

| Changes from Revision A (September 2009) to Revision B (December 2023) | Page |
|------------------------------------------------------------------------------------------------------------------------------|------|
| • 更改了整个文档中的表格、图和交叉参考的编号格式..... | 1 |
| • Added the <i>ESD Ratings</i> tables..... | 3 |
| • Added the <i>Thermal Information</i> table..... | 4 |
| • Changed the I _{CC} Auto-powerdown disabled max value from 1 mA to 1.3 mA in the <i>Electrical Characteristics</i> | 4 |

| Changes from Revision * (January 2006) to Revision A (September 2009) | Page |
|-----------------------------------------------------------------------|------|
| • 删除了 <i>RHL</i> 引脚排列图..... | 1 |

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|----------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| MAX3223ECDB | Obsolete | Production | SSOP (DB) 20 | - | - | Call TI | Call TI | 0 to 70 | MP223EC |
| MAX3223ECDBR | Obsolete | Production | SSOP (DB) 20 | - | - | Call TI | Call TI | 0 to 70 | MP223EC |
| MAX3223ECDW | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | MAX3223EC |
| MAX3223ECDW.A | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | MAX3223EC |
| MAX3223ECDWR | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | MAX3223EC |
| MAX3223ECDWR.A | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | MAX3223EC |
| MAX3223ECPW | Obsolete | Production | TSSOP (PW) 20 | - | - | Call TI | Call TI | 0 to 70 | MP223EC |
| MAX3223ECPWR | Obsolete | Production | TSSOP (PW) 20 | - | - | Call TI | Call TI | 0 to 70 | MP223EC |
| MAX3223EIDB | Obsolete | Production | SSOP (DB) 20 | - | - | Call TI | Call TI | -40 to 85 | MP223EI |
| MAX3223EIDBR | Active | Production | SSOP (DB) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MP223EI |
| MAX3223EIDBR.A | Active | Production | SSOP (DB) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MP223EI |
| MAX3223EIDBRG4 | Active | Production | SSOP (DB) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MP223EI |
| MAX3223EIDBRG4.A | Active | Production | SSOP (DB) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MP223EI |
| MAX3223EIDW | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MAX3223EI |
| MAX3223EIDW.A | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MAX3223EI |
| MAX3223EIDWR | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MAX3223EI |
| MAX3223EIDWR.A | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MAX3223EI |
| MAX3223EIPWR | Active | Production | TSSOP (PW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MP223EI |
| MAX3223EIPWR.A | Active | Production | TSSOP (PW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | MP223EI |

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| MAX3223ECDWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| MAX3223EIDBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| MAX3223EIDBRG4 | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| MAX3223EIDWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| MAX3223EIPWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| MAX3223ECDWR | SOIC | DW | 20 | 2000 | 356.0 | 356.0 | 45.0 |
| MAX3223EIDBR | SSOP | DB | 20 | 2000 | 353.0 | 353.0 | 32.0 |
| MAX3223EIDBRG4 | SSOP | DB | 20 | 2000 | 353.0 | 353.0 | 32.0 |
| MAX3223EIDWR | SOIC | DW | 20 | 2000 | 356.0 | 356.0 | 45.0 |
| MAX3223EIPWR | TSSOP | PW | 20 | 2000 | 353.0 | 353.0 | 32.0 |

TUBE


*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|---------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| MAX3223ECDW | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| MAX3223ECDW.A | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| MAX3223EIDW | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| MAX3223EIDW.A | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |

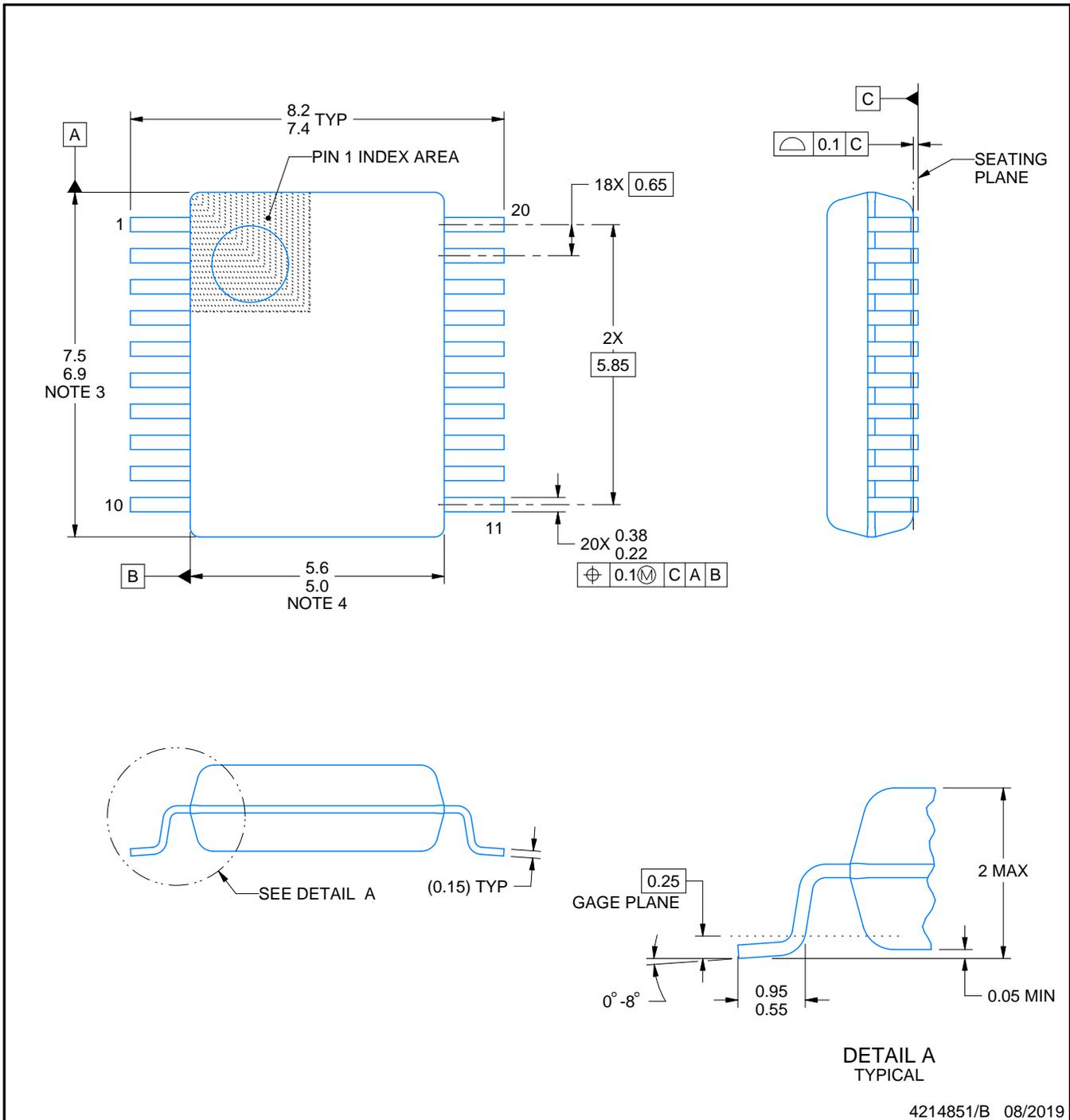
DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



4214851/B 08/2019

NOTES:

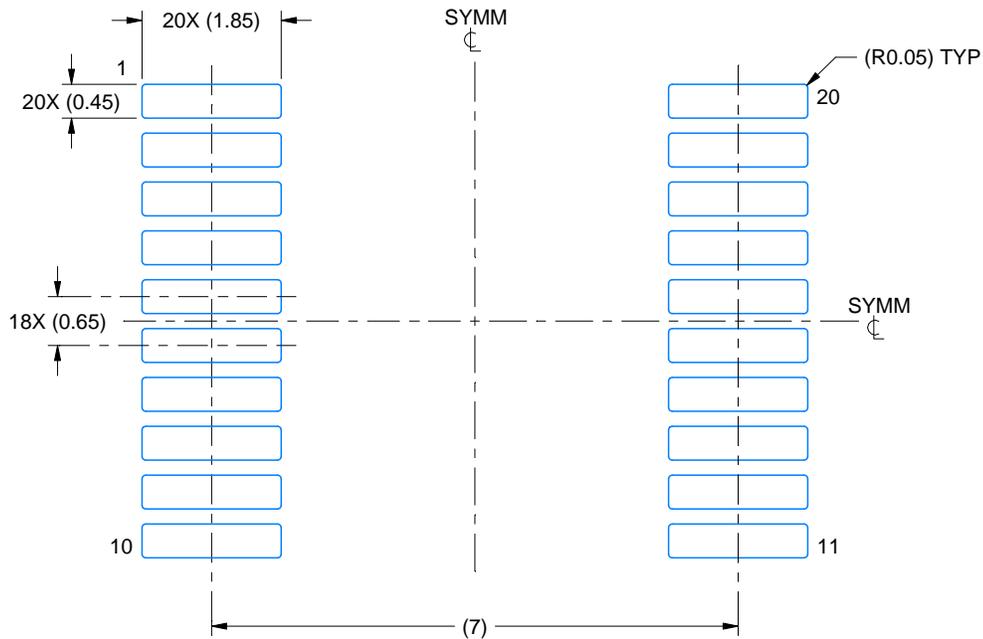
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

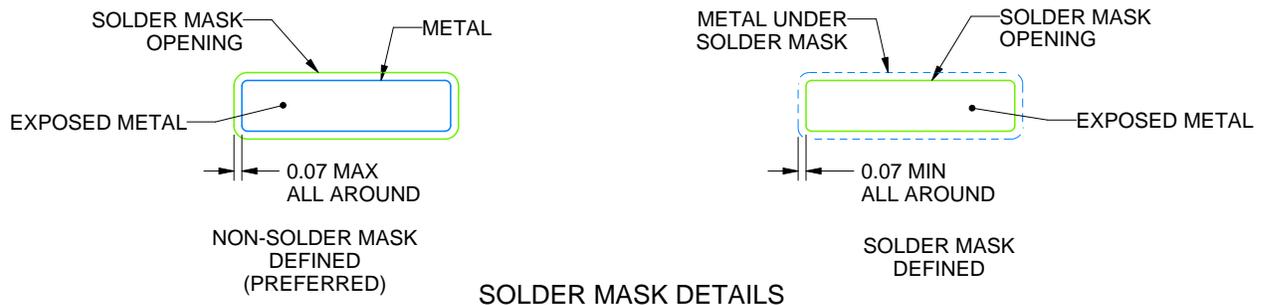
DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4214851/B 08/2019

NOTES: (continued)

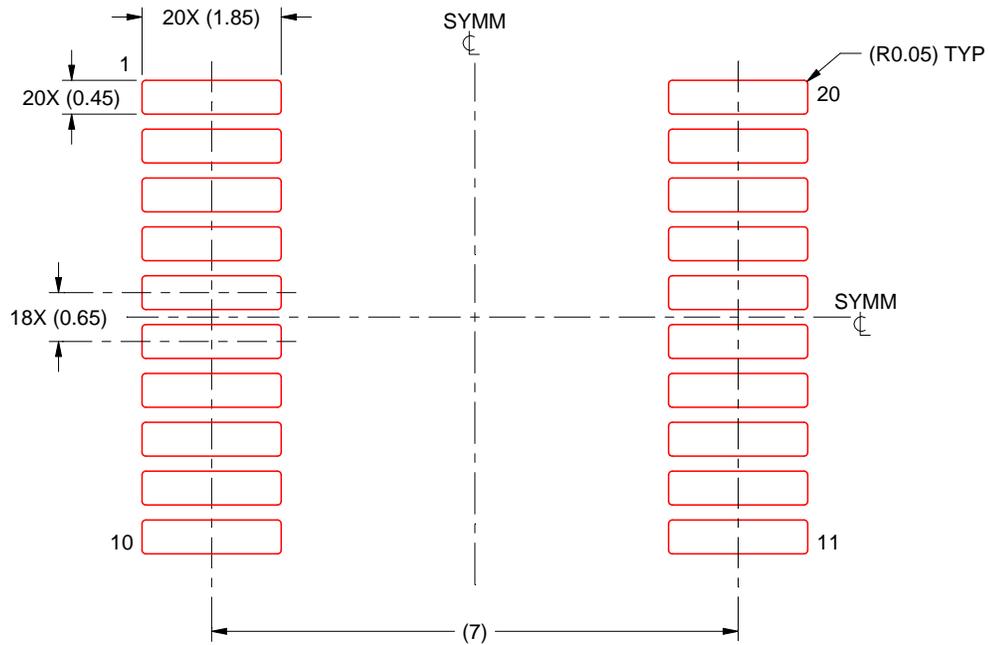
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4214851/B 08/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

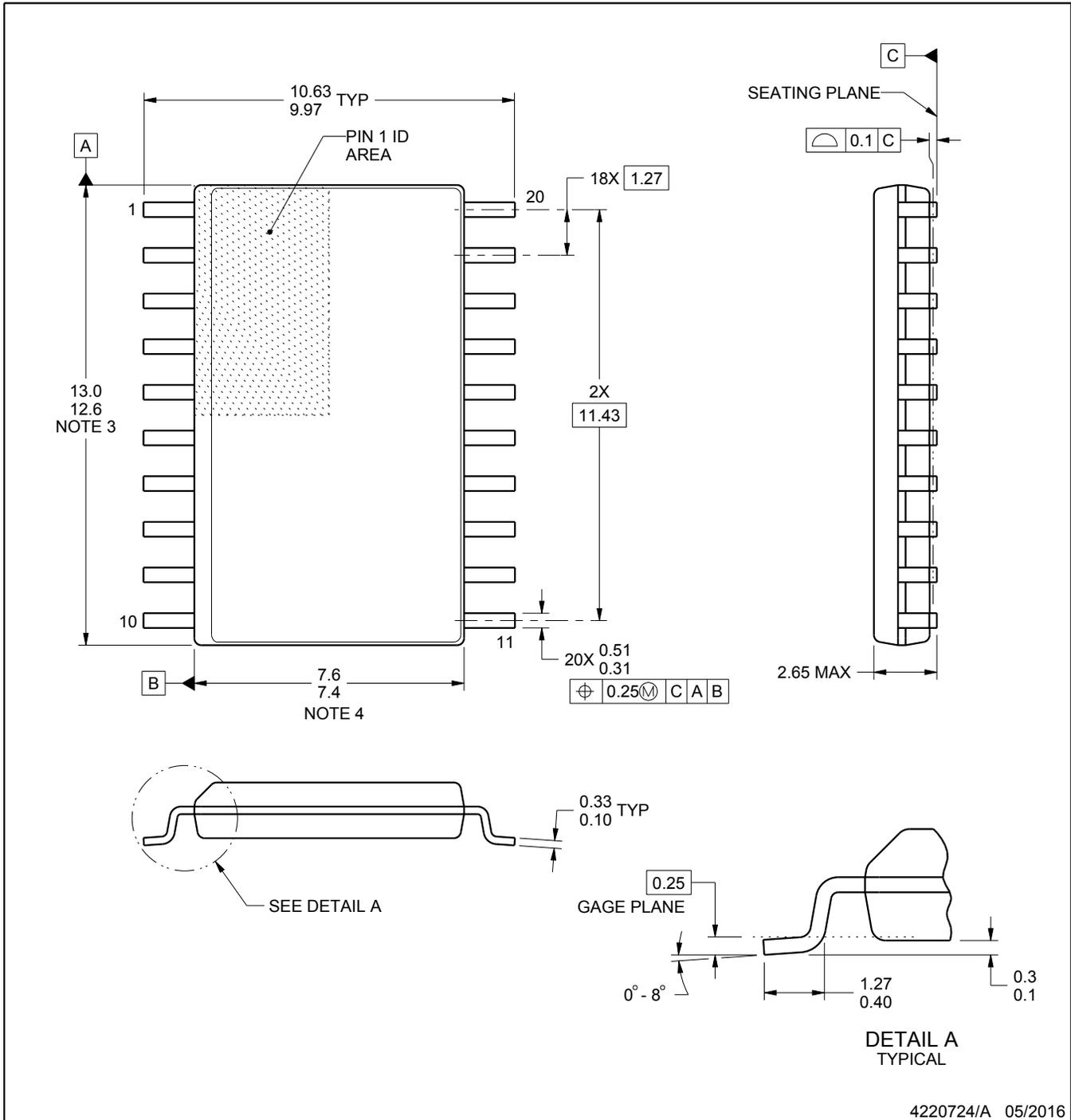
DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4220724/A 05/2016

NOTES:

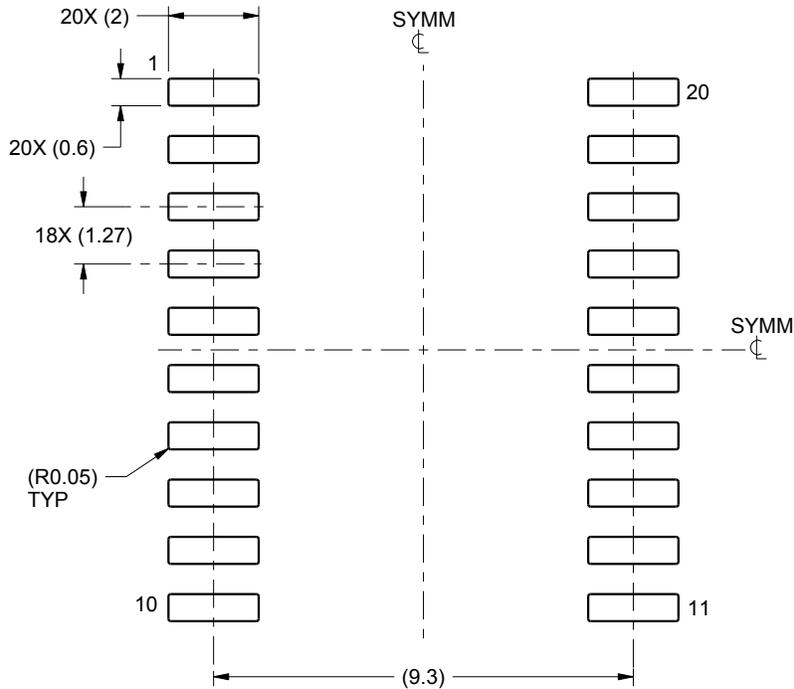
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2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

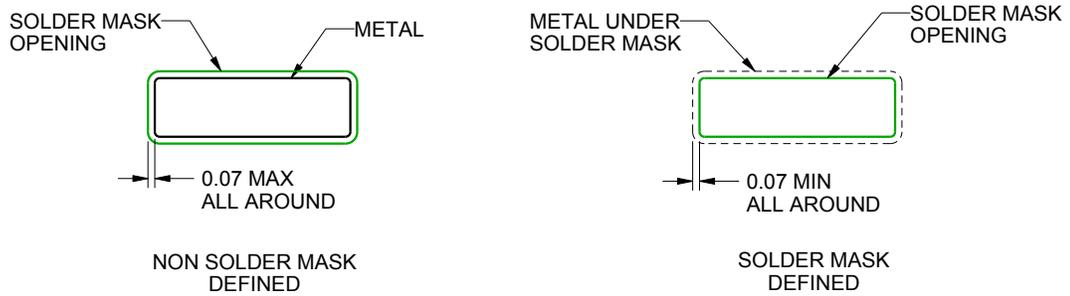
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

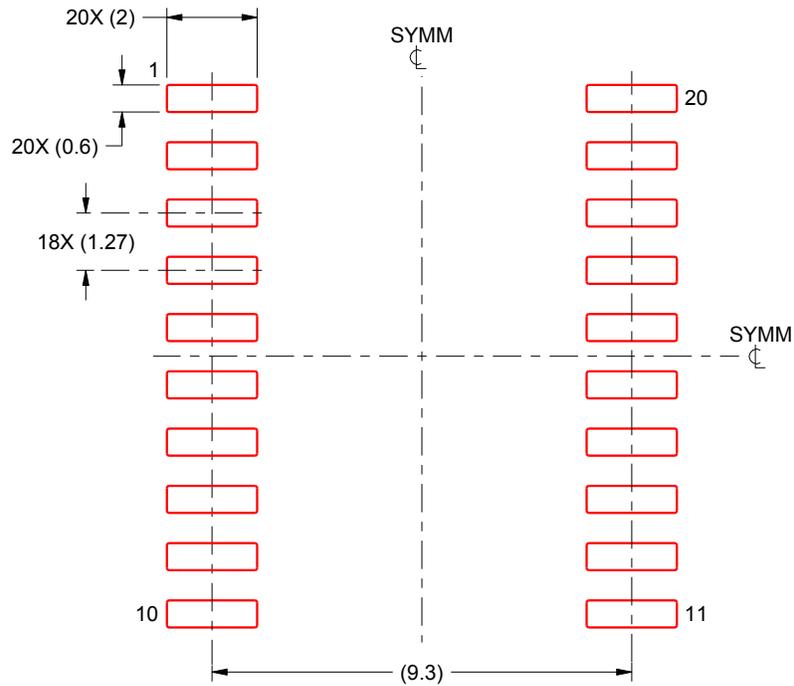
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

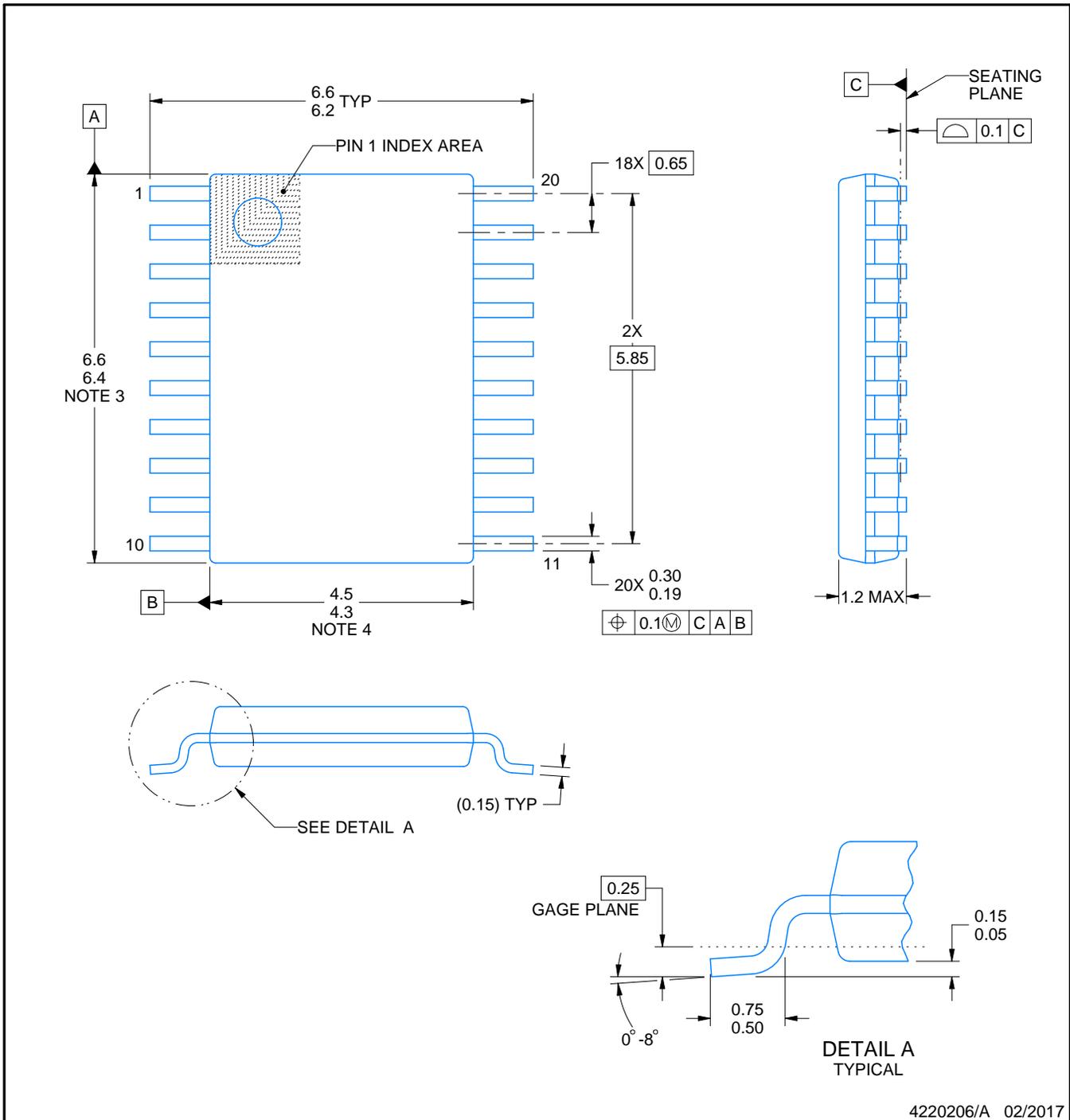
PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220206/A 02/2017

NOTES:

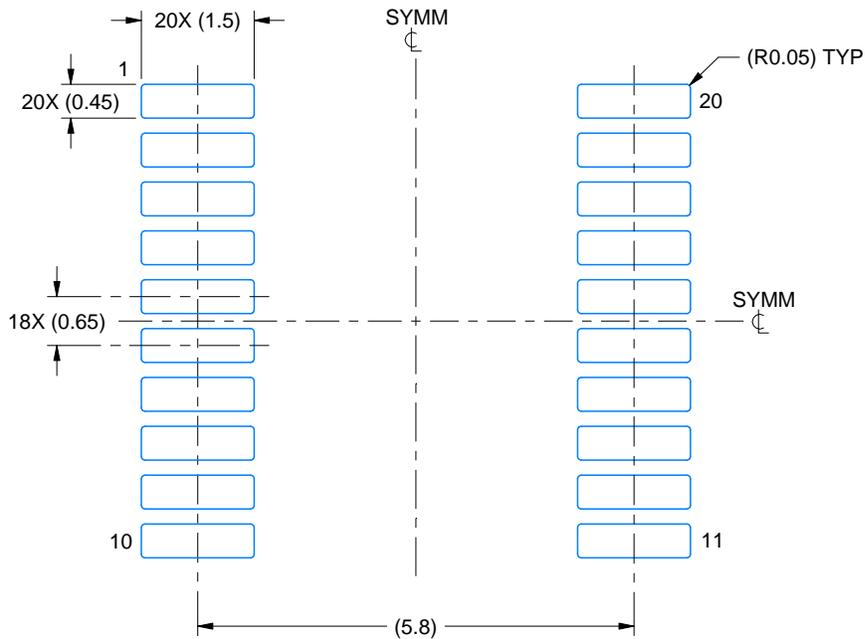
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

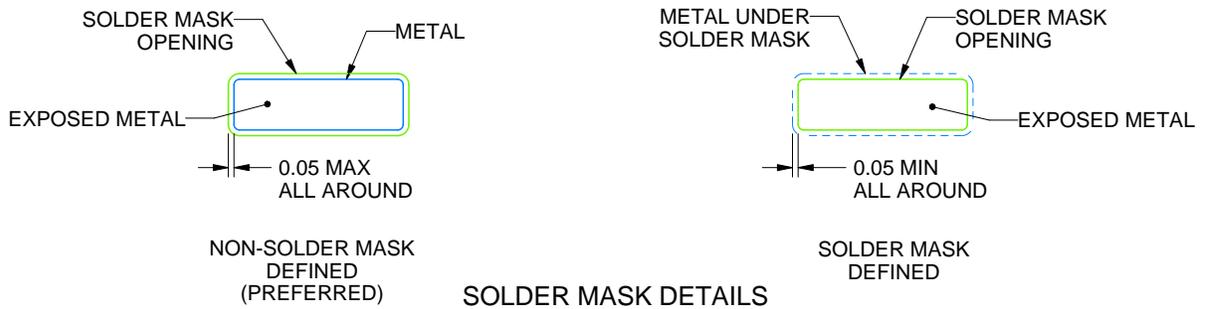
PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220206/A 02/2017

NOTES: (continued)

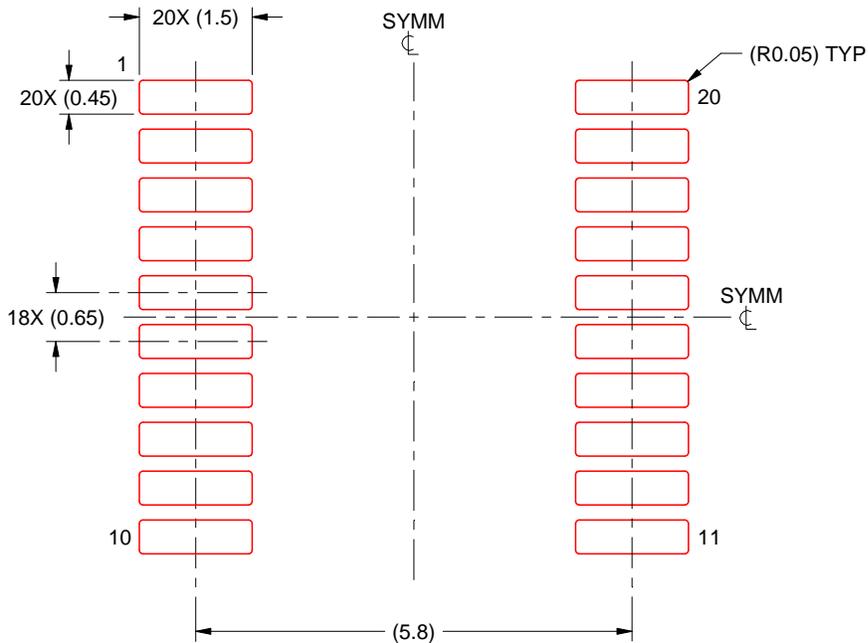
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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